

# SANYO Semiconductors DATA SHEET

# 2SK3823— General-Purpose Switching Device Applications

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.
- · Motor drive, DC / DC converter.
- · Avalanche resistance guarantee.

# **Specifications**

#### **Absolute Maximum Ratings** at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		40	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	160	Α
Allowable Power Dissipation	D-		1.75	W
	PD	Tc=25°C	45	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		56	mJ
Avalanche Current *2	IAV		40	Α

Note: \*1 VDD=20V, L=50µH, IAV=40A

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	60			V
Zero-Gate Voltage Drain Current	IDSS	VDS=60V, VGS=0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> = ±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	Vgs(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =20A	16	28		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =20A, V <sub>GS</sub> =10V		21	27.5	mΩ
	R <sub>DS</sub> (on)2	I <sub>D</sub> =20A, V <sub>GS</sub> =4V		29	41	mΩ

Marking: K3823 Continued on next page.

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<sup>\*2</sup> L≤50μH, Single pulse

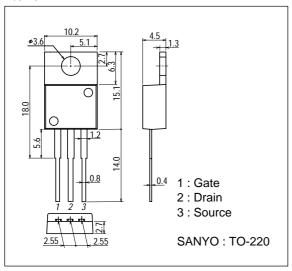
## 2SK3823

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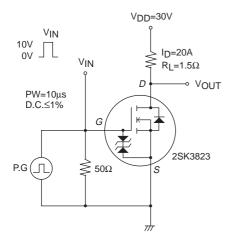
Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		1780		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		266		pF
Reverse Transfer Capacitance	Crss	VDS=20V, f=1MHz		197		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		16.5		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		160		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		160		ns
Fall Time	tf	See specified Test Circuit.		160		ns
Total Gate Charge	Qg	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =40A		40		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =40A		6.5		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =40A		11.5		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =40A, V <sub>GS</sub> =0		1.08	1.5	V

# **Package Dimensions**

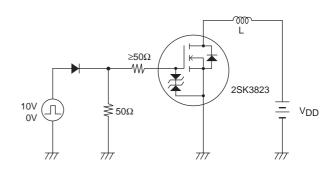
unit : mm 2052C

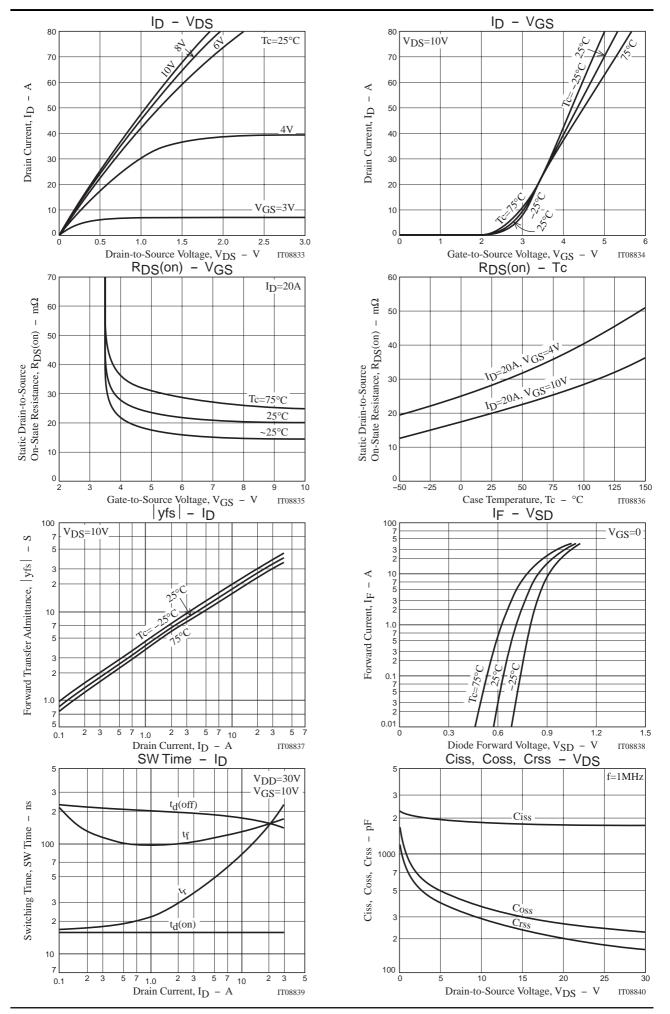


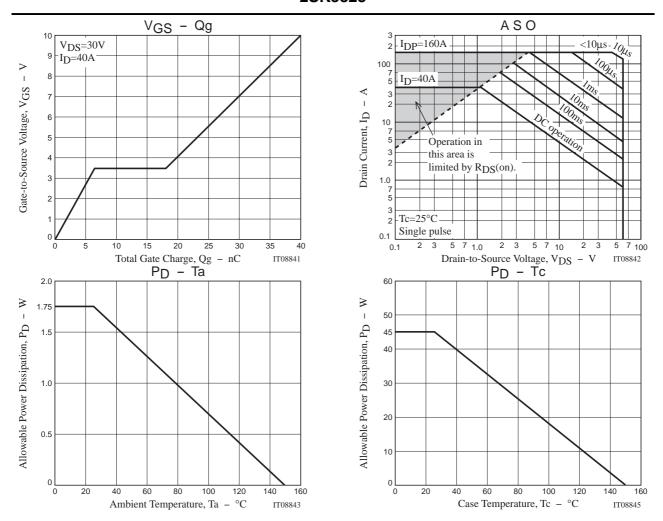
# **Switching Time Test Circuit**



## **Avalanche Resistance Test Circuit**







Note on usage: Since the 2SK3823 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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